

MOS FIELD EFFECT TRANSISTOR μ PA1764

SWITCHING DUAL N-CHANNEL POWER MOS FET INDUSTRIAL USE

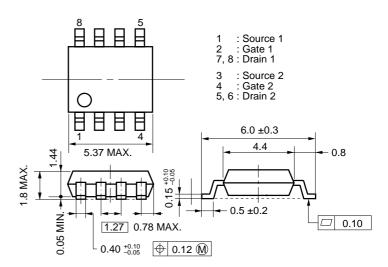
DESCRIPTION

The μ PA1764 is N-channel MOS Field Effect Transistor designed for high current switching applications.

FEATURES

- Dual chip type
- Low On-state Resistance
- ★ RDS(on)1 = 27 m Ω (TYP.) (VGS = 10 V, ID = 3.5 A)
- ★ RDS(on)2 = 32 m Ω (TYP.) (VGS = 4.5 V, ID = 3.5 A)
- ★ RDS(on)3 = 34 m Ω (TYP.) (VGS = 4.0 V, ID = 3.5 A)
 - · Low input capacitance
- ★ C_{iss} = 1300 pF (TYP.)
 - Built-in G-S protection diode
 - Small and surface mount package (Power SOP8)

PACKAGE DRAWING (Unit: mm)



ORDERING INFORMATION

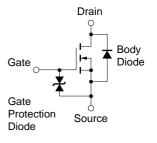
PART NUMBER	PACKAGE
μPA1764G	Power SOP8

EQUIVALENT CIRCUIT

(1/2 circuit)

ABSOLUTE MAXIMUM RATINGS (T_A = 25°C, All terminals are connected.) Drain to Source Voltage V_{DSS} 60 V

Drain to Source Voltage	VDSS	60	V	
Gate to Source Voltage	Vgss	±20	V	
Drain Current (DC)	I _{D(DC)}	±7	Α	
Drain Current (pulse) Note1	ID(pulse)	±28	Α	
Total Power Dissipation (1 unit) Note2	Рт	1.7	W	
Total Power Dissipation (2 unit) Note2	PT	2.0	W	
Channel Temperature	Tch	150	°C	
Storage Temperature	Tstg	-55 to +150	°C	
Single Avalanche Current Note3	las	7	Α	
Single Avalanche Energy Note3	Eas	98	mJ	



- **Notes 1.** PW \leq 10 μ s, Duty Cycle \leq 1 %
 - 2. Mounted on ceramic substrate of 2000 mm² x 2.2 mm
 - 3. Starting Tch = 25 °C, Rg = 25 Ω , Vgs = 20 V \rightarrow 0 V

Remark The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

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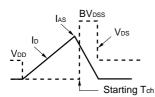
Not all devices/types available in every country. Please check with local NEC representative for availability and additional information.



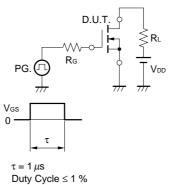
★ ELECTRICAL CHARACTERISTICS (T_A = 25 °C, All terminals are connected.)

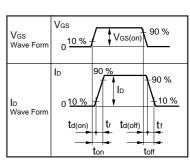
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CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Drain to Source On-state Resistance	RDS(on)1	Vgs = 10 V, ID = 3.5 A		27	35	mΩ
	RDS(on)2	Vgs = 4.5 V, ID = 3.5 A		32	42	mΩ
	RDS(on)3	Vgs = 4.0 V, ID = 3.5 A		34	46	mΩ
Gate to Source Cut-off Voltage	V _{GS(off)}	V _{DS} = 10 V, I _D = 1 mA	1.5	2.0	2.5	V
Forward Transfer Admittance	y _{fs}	V _{DS} = 10 V, I _D = 3.5 A	5.0	9.0		S
Drain Leakage Current	IDSS	Vps = 60 V, Vgs = 0 V			10	μΑ
Gate to Source Leakage Current	Igss	Vgs = ±20 V, Vps = 0 V			±10	μΑ
Input Capacitance	Ciss	Vps = 10 V		1300		pF
Output Capacitance	Coss	Vgs = 0 V		230		pF
Reverse Transfer Capacitance	Crss	f = 1 MHz		110		pF
Turn-on Delay Time	t _{d(on)}	ID = 3.5 A		15		ns
Rise Time	tr	VGS(on) = 10 V		69		ns
Turn-off Delay Time	t _{d(off)}	VDD = 30 V		65		ns
Fall Time	t f	$R_G = 10 \Omega$		27		ns
Total Gate Charge	Q _G	ID = 7.0 A		29		nC
Gate to Source Charge	Qgs	VDD = 48 V		3.6		nC
Gate to Drain Charge	QGD	Vgs = 10 V		7.4		nC
Body Diode Forward Voltage	V _{F(S-D)}	IF = 7.0 A, VGS = 0 V		0.84		V
Reverse Recovery Time	trr	IF = 7.0 A, VGS = 0 V		40		ns
Reverse Recovery Charge	Qrr	di/dt = 100 A / μs		66		nC

TEST CIRCUIT 1 AVALANCHE CAPABILITY

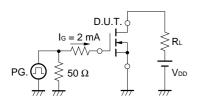


TEST CIRCUIT 2 SWITCHING TIME





TEST CIRCUIT 3 GATE CHARGE



NEC μ PA1764

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